

# General purpose (dual digital transistors )

## UMH11N / IMH11A

### ●Features

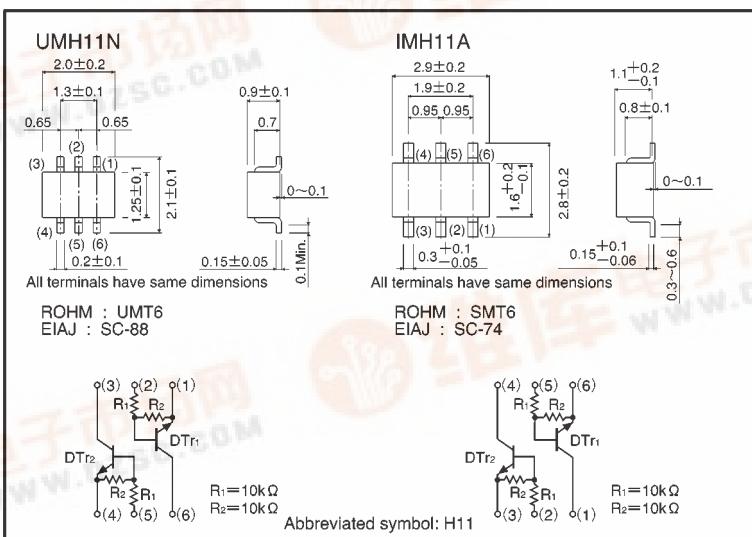
- 1) Two DTC114E chips in a UMT or SMT package.
- 2) Mounting possible with UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

### ●Structure

Epitaxial planar type  
NPN silicon transistor  
(Built-in resistor type)

The following characteristics apply to both DT<sub>r1</sub> and DT<sub>r2</sub>.

### ●External dimensions (Units: mm)



### ●Absolute maximum ratings (Ta = 25°C)

| Parameter            | Symbol                | Limits     | Unit  |
|----------------------|-----------------------|------------|-------|
| Supply voltage       | V <sub>cc</sub>       | 50         | V     |
| Input voltage        | V <sub>IN</sub>       | 40         | V     |
|                      |                       | -10        |       |
| Output current       | I <sub>o</sub>        | 50         | mA    |
| Collector current    | I <sub>c</sub> (Max.) | 100        | mA    |
| Power dissipation    | P <sub>d</sub>        | 150(TOTAL) | mW *1 |
|                      |                       | 300(TOTAL) |       |
| Junction temperature | T <sub>j</sub>        | 150        | °C    |
| Storage temperature  | T <sub>stg</sub>      | -55~+150   | °C    |

\*1 120mW per element must not be exceeded.

\*2 200mW per element must not be exceeded.

# Transistors

# UMH11N / IMH11A

## ● Electrical characteristics ( $T_a = 25^\circ\text{C}$ )

| Parameter            | Symbol              | Min. | Typ. | Max. | Unit          | Conditions                                               |
|----------------------|---------------------|------|------|------|---------------|----------------------------------------------------------|
| Input voltage        | $V_{I(\text{off})}$ | —    | —    | 0.5  | V             | $V_{cc}=5\text{V}, I_o=100\ \mu\text{A}$                 |
|                      | $V_{I(\text{on})}$  | 3    | —    | —    |               | $V_o=0.3\text{V}, I_o=10\text{mA}$                       |
| Output voltage       | $V_{O(\text{on})}$  | —    | 0.1  | 0.3  | V             | $I_o/I_i=10\text{mA}/0.5\text{mA}$                       |
| Input current        | $I_i$               | —    | —    | 0.88 | mA            | $V_i=5\text{V}$                                          |
| Output current       | $I_o(\text{off})$   | —    | —    | 0.5  | $\mu\text{A}$ | $V_{cc}=50\text{V}, V_i=0\text{V}$                       |
| DC current gain      | $G_i$               | 30   | —    | —    | —             | $V_o=5\text{V}, I_o=5\text{mA}$                          |
| Transition frequency | $f_T$               | —    | 250  | —    | MHz           | $V_{CE}=10\text{mA}, I_E=-5\text{mA}, f=100\text{MHz}^*$ |
| Input resistance     | $R_i$               | 7    | 10   | 13   | k $\Omega$    | —                                                        |
| Resistance ratio     | $R_2/R_1$           | 0.8  | 1    | 1.2  | —             | —                                                        |

\* Transition frequency of the device

## ● Packaging specifications

| Part No. | Packaging type               | Taping |      |
|----------|------------------------------|--------|------|
|          | Code                         | TN     | T110 |
|          | Basic ordering unit (pieces) | 3000   | 3000 |
| UMH11N   | ○                            | —      |      |
| IMH11A   | —                            | ○      |      |

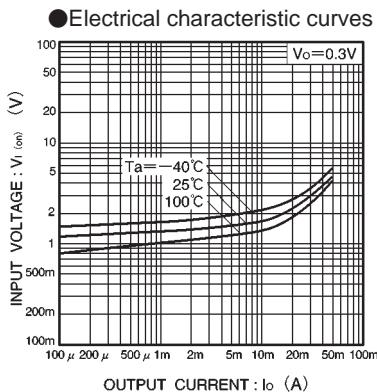


Fig.1 Input voltage vs. output current (ON characteristics)

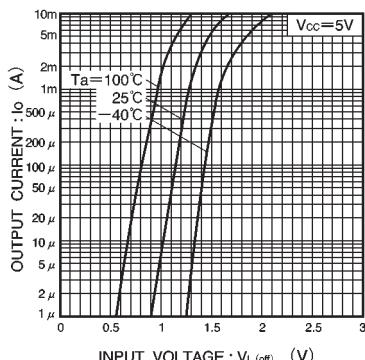


Fig.2 Output current vs. input voltage (OFF characteristics)

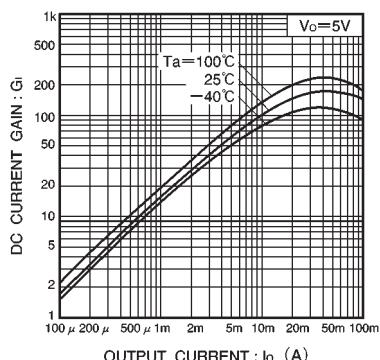


Fig.3 DC current gain vs. output current

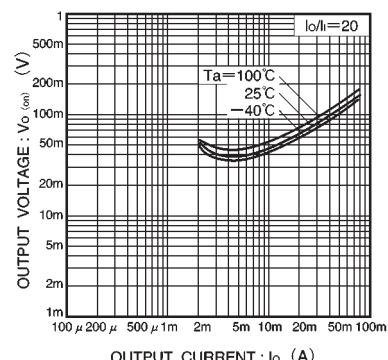


Fig.4 Output voltage vs. output current